

FAST CMOS 16-BIT REGISTER (3-STATE)

IDT74FCT16374AT/CT/ET

FEATURES:

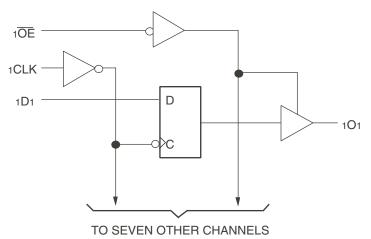
- 0.5 MICRON CMOS Technology
- · High-speed, low-power CMOS replacement for ABT functions
- Typical tSK(o) (Output Skew) < 250ps
- Low input and output leakage ≤1µA (max.)
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- $VCC = 5V \pm 10\%$
- High drive outputs (-32mA IOH, 64mA IOL)
- · Power off disable outputs permit "live insertion"
- Typical VolP (Output Ground Bounce) < 1.0V at Vcc = 5V, TA = 25°C
- · Available in the following packages:
 - Industrial: SSOP, TSSOP

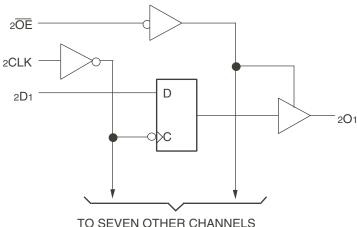
DESCRIPTION:

The FCT16374T 16-bit edge-triggered D-type register is built using advanced dual metal CMOS technology. These high-speed, low-power registers are ideal for use as buffer registers for data synchronization and storage. The Output Enable ($\overline{\text{XOE}}$) and clock (xCLK) controls are organized to operate each device as two 8-bit registers or one 16-bit register with common clock. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

The FCT16374T is ideally suited for driving high-capacitance loads and low-impedance backplanes. The output buffers are designed with power off disable capability to allow "live insertion" of boards when used as backplane drivers.

FUNCTIONAL BLOCK DIAGRAM

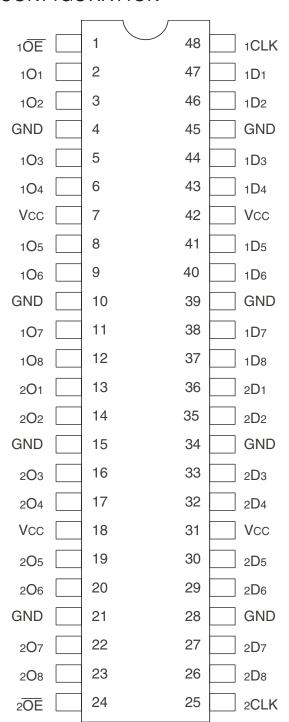




INDUSTRIAL TEMPERATURE RANGE

MARCH 2019

PIN CONFIGURATION



TOP VIEW

Package Type Package Type	Package Code	Order Code
TSSOP	PAG48	PAG
SSOP	PVG48	PVG

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to 7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	٧
Tstg	Storage Temperature	-65 to +150	°C
Іоит	DC Output Current	-60 to +120	mA

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. All device terminals except FCT162XXX Output and I/O terminals.
- 3. Outputs and I/O terminals for FCT162XXX.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

S	ymbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
С	IN	Input Capacitance	VIN = 0V	3.5	6	рF
С	OUT	Output Capacitance	Vout = 0V	3.5	8	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description	
хDх	Data Inputs	
xCLK	Clock Inputs	
хОх	3-State Outputs	
×ŌĒ	3-State Output Enable Input (Active LOW)	

FUNCTION TABLE(1)

		Outputs		
Function	хDх	xCLK	× OE	хОх
Z	Х	L	Н	Z
	Х	Н	Н	Z
Load	L	1	L	L
Register	Н	1	L	Н
	L	1	Н	Z
	Н	1	Н	Z

NOTE:

- 1. H = HIGH voltage level
 - L = LOW voltage level
 - X = Don't care
 - Z = High-impedance
 - ↑ = LOW-to-HIGH transition

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C, VCC = 5.0V ± 10 %

Symbol	Parameter	Test Conditions ⁽	1)	Min.	Typ. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH Level		2	_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW Level		_	_	0.8	V
Iн	Input HIGH Current (Input pins) ⁽⁵⁾	Vcc = Max.	VI = VCC	_	_	±1	μΑ
	Input HIGH Current (I/O pins) ⁽⁵⁾			_	_	±1	
lıL	Input LOW Current (Input pins) ⁽⁵⁾		VI = GND	_	_	±1	
	Input LOW Current (I/O pins) ⁽⁵⁾				_	±1	
lozн	High Impedance Output Current	Vcc = Max.	Vo = 2.7V	_	_	±1	μΑ
lozL	(3-State Output pins) ⁽⁵⁾		Vo = 0.5V	_	_	±1	
VIK	Clamp Diode Voltage	VCC = Min., IIN = -18mA		_	-0.7	-1.2	V
los	Short Circuit Current	Vcc = Max., Vo = GND ⁽³⁾		-80	-140	-250	mA
VH	Input Hysteresis	_		_	100	1	mV
ICCL	Quiescent Power Supply Current	Vcc = Max		_	5	500	μА
Іссн		Vin = GND or Vcc					
Iccz							

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
lo	Output Drive Current	$Vcc = Max., Vo = 2.5V^{(3)}$		-50	1	-180	mA
Vон	Output HIGH Voltage	Vcc = Min.	IOH = -3mA	2.5	3.5	ı	V
		Vcc = Min.	IOH = -15mA IND	2.4	3.5	I	V
			IOH = -32mA IND	2	3	-	V
VoL	Output LOW Voltage	Vcc = Min.	IOL = 64mA IND	_	0.2	0.55	V
		VIN = VIH or VIL					
IOFF	Input/Output Power Off Leakage ⁽⁵⁾	$VCC = 0V$, $VIN = or VO \le 4.5V$		_	_	±1	μΑ

NOTES

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V, $+25^{\circ}C$ ambient.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. Duration of the condition can not exceed one second.
- 5. This test limit for this parameter is $\pm 5\mu A$ at $T_A = -55^{\circ} C$.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	$VCC = Max.$ $VIN = 3.4V^{(3)}$		_	0.5	1.5	mA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open xOE = GND One Input Toggling 50% Duty Cycle	VIN = VCC VIN = GND	_	60	100	μA/ MHz
Ic	Total Power Supply Current ⁽⁶⁾	Vcc = Max. Outputs Open fcP = 10MHz 50% Duty Cycle $x\overline{OE}$ = GND fi = 5MHz	VIN = VCC VIN = GND VIN = 3.4V VIN = GND	_	1.1	1.5	mA
		50% Duty Cycle One Bit Toggling					
		Vcc = Max. Outputs Open fcP = 10MHz 50% Duty Cycle	VIN = VCC VIN = GND	_	3	5.5 ⁽⁵⁾	
		xOE = GND Sixteen Bits Toggling fi = 2.5MHz 50% Duty Cycle	VIN = 3.4V VIN = GND	_	7.5	19 ⁽⁵⁾	

NOTES:

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V, +25°C ambient.
- 3. Per TTL driven input (VIN = 3.4V). All other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- 5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.
- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
 - $\mbox{IC} = \mbox{ICC} + \Delta \mbox{ICC} \mbox{ DHNT} + \mbox{ICCD} \mbox{ (fcpNcp/2} + \mbox{fiNi)}$
 - Icc = Quiescent Current (IccL, IccH and Iccz)
 - ΔIcc = Power Supply Current for a TTL High Input (VIN = 3.4V)
 - DH = Duty Cycle for TTL Inputs High
 - NT = Number of TTL Inputs at DH
 - ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
 - fcP = Clock Frequency for Register Devices (Zero for Non-Register Devices)
 - NCP = Number of Clock Inputs at fCP
 - fi = Input Frequency
 - Ni = Number of Inputs at fi

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

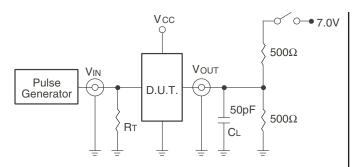
			74FCT16374AT		
			ı	nd.	
Symbol	Parameter	Condition ⁽²⁾	Min. ⁽²⁾	Max.	Unit
tPLH	Propagation Delay	CL = 50pF	2	6.5	ns
tPHL	xCLK to xOx	$RL = 500\Omega$			
tpzh	Output Enable Time		1.5	6.5	ns
tPZL					
tPHZ	Output Disable Time		1.5	5.5	ns
tPLZ					
tsu	Set-up Time HIGH or LOW, xDx to xCLK		2		ns
tH	Hold Time HIGH or LOW, xDx to xCLK		1.5		ns
tw	xCLK Pulse Width HIGH or LOW		5	_	ns
tsk(o)	Output Skew ⁽³⁾		_	0.5	ns

			74FCT16374CT		74FCT16374CT 74FCT16374ET		6374ET	
			In	d.	In	d.		
Symbol	Parameter	Condition ⁽²⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit	
tPLH	Propagation Delay	CL = 50pF	2	5.2	1.5	3.7	ns	
tPHL	xCLK to xOx	$RL = 500\Omega$						
tpzh	Output Enable Time		1.5	5.5	1.5	4.4	ns	
tpzl								
tPHZ	Output Disable Time		1.5	5	1.5	3.6	ns	
tPLZ								
tsu	Set-up Time HIGH or LOW, xDx to xCLK		2	_	1.5		ns	
tH	Hold Time HIGH or LOW, xDx to xCLK		1.5	_	0		ns	
tw	xCLK Pulse Width HIGH or LOW		5	_	3 ⁽⁴⁾	_	ns	
tSK(o)	Output Skew ⁽³⁾		_	0.5	_	0.5	ns	

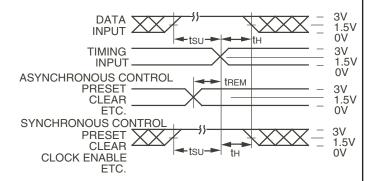
NOTES:

- 1. See test circuit and waveforms.
- 2. Minimum limits are guaranteed but not tested.
- 3. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.
- 4. This limit is guaranteed but not tested.

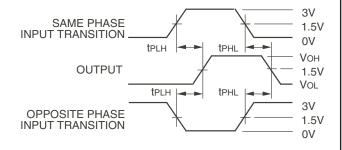
TEST CIRCUITS AND WAVEFORMS



Test Circuits for All Outputs



Set-up, Hold, and Release Times



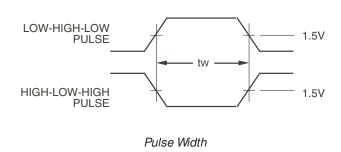
Propagation Delay

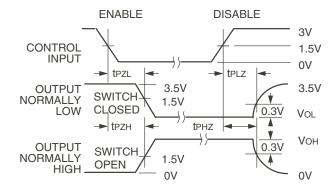
SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

DEFINITIONS:

- CL = Load capacitance: includes jig and probe capacitance.
- RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.



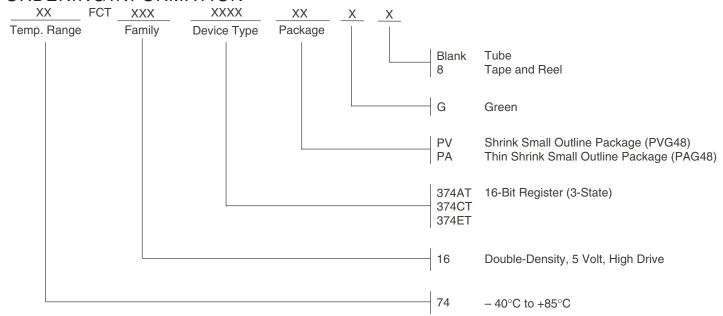


Enable and Disable Times

NOTES:

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns.

ORDERING INFORMATION



Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
Α	74FCT16374ATPAG	PAG48	TSSOP	I
	74FCT16374ATPAG8	PAG48	TSSOP	I
	74FCT16374ATPVG	PVG48	SSOP	I
	74FCT16374ATPVG8	PVG48	SSOP	I
С	74FCT16374CTPAG	PAG48	TSSOP	I
	74FCT16374CTPAG8	PAG48	TSSOP	ı
	74FCT16374CTPVG	PVG48	SSOP	-
	74FCT16374CTPVG8	PVG48	SSOP	ı
Е	74FCT16374ETPAG	PAG48	TSSOP	ı
	74FCT16374ETPAG8	PAG48	TSSOP	I
	74FCT16374ETPVG	PVG48	SSOP	Ī
	74FCT16374ETPVG8	PVG48	SSOP	I

Datasheet Document History

09/28/2009	Pg. 7	Updated the ordering information by removing the "IDT" notation and non RoHS part.
05/22/2018	Pg. 1, 2, 5, 7	Added table under pin configuration diagram with detailed package information. Updated the ordering information
		diagram by deleting 54FCT, MIL, Cerpack package and adding Tube, Tape and Reel.
		Added orderable part information table.
08/06/2018	Pg. 7	Corrected ordering information diagram symbol for "-"43
03/26/2019	Pg. 7	Typo in above text; should be -40 Not -43

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